

HD74HC109

Dual J- $\overline{K}$ Flip-Flops (with Preset and Clear)

HITACHI

Description

Each flip-flop has independent J, $\overline{K}$, preset, clear and clock inputs and Q and $\overline{Q}$ outputs. This device is edge sensitive to the clock input and changes state on the positive going transition of the clock pulse. Clear and preset are independent of the clock and accomplished by a low logic level on the corresponding input.

Features

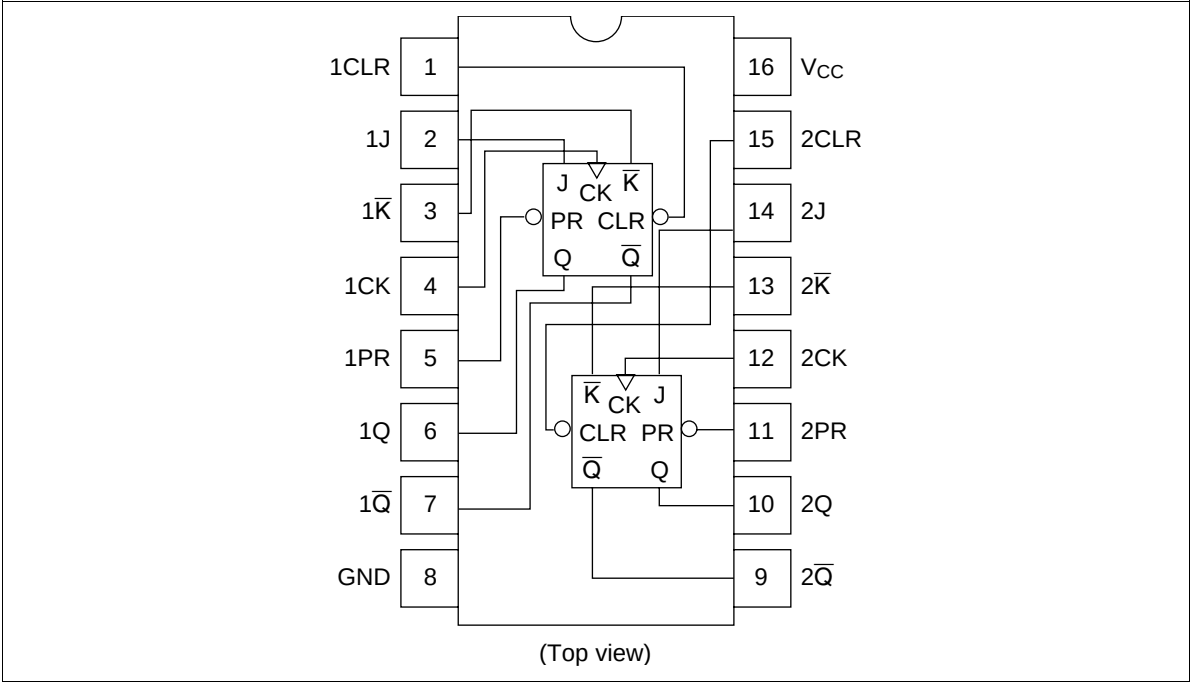
- High Speed Operation: t_{pd} (Clock to Q) = 15 ns typ (C_L = 50 pF)
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage: V_{CC} = 2 to 6 V
- Low Input Current: 1 μ A max
- Low Quiescent Supply Current: I_{CC} (static) = 2 μ A max (T_a = 25°C)

Function Table

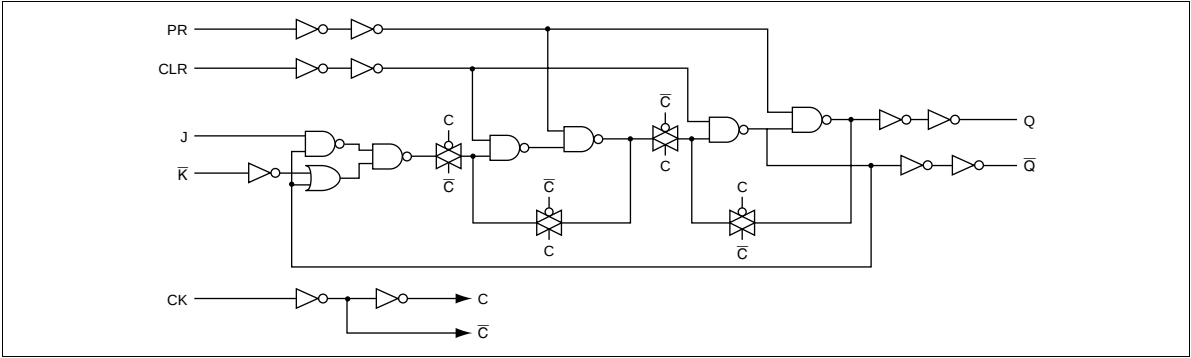
Inputs					Output	
Preset	Clear	Clock	J	$\overline{K}$	Q	$\overline{Q}$
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	H* ¹	H* ¹
H	H		L	L	L	H
H	H		H	L	Toggle	
H	H		L	H	Q ₀	$\overline{Q}_0$
H	H		H	H	H	L
H	H	L	X	X	Q ₀	$\overline{Q}_0$

Note: 1. Q and $\overline{Q}$ will remain high as long as preset and clear input are low, but Q and $\overline{Q}$ are unpredictable if preset and clear input go high simultaneously.

Pin Arrangement



Block Diagram (1/2)



DC Characteristics

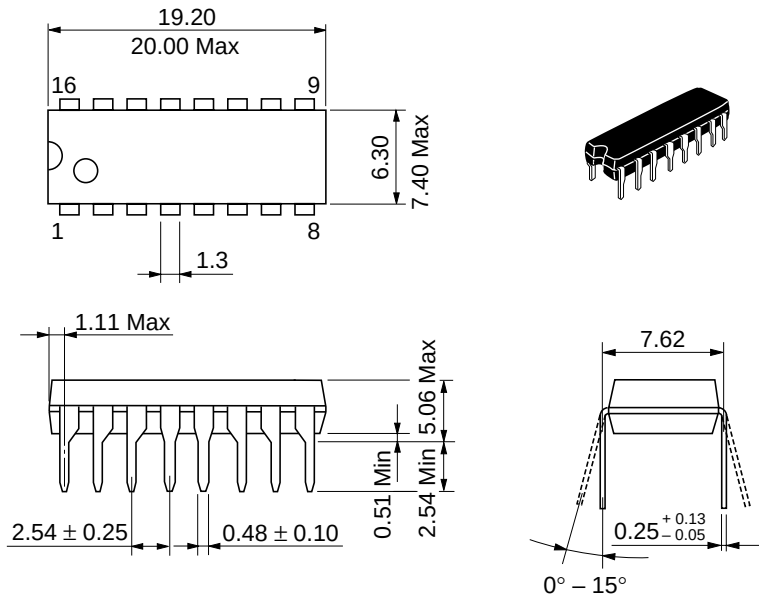
Item	Symbol	V _{CC} (V)	Ta = 25°C			Ta = -40 to +85°C		Unit	Test Conditions	
			Min	Typ	Max	Min	Max			
Input voltage	V _{IH}	2.0	1.5	—	—	1.5	—	V		
		4.5	3.15	—	—	3.15	—			
		6.0	4.2	—	—	4.2	—			
	V _{IL}	2.0	—	—	0.5	—	0.5	V		
		4.5	—	—	1.35	—	1.35			
		6.0	—	—	1.8	—	1.8			
Output voltage	V _{OH}	2.0	1.9	2.0	—	1.9	—	V	Vin = V _{IH} or V _{IL} I _{OH} = -20 μA	
		4.5	4.4	4.5	—	4.4	—			
		6.0	5.9	6.0	—	5.9	—			
		4.5	4.18	—	—	4.13	—			I _{OH} = -4 mA
		6.0	5.68	—	—	5.63	—			I _{OH} = -5.2 mA
	V _{OL}	2.0	—	0.0	0.1	—	0.1	V	Vin = V _{IH} or V _{IL} I _{OL} = 20 μA	
		4.5	—	0.0	0.1	—	0.1			
		6.0	—	0.0	0.1	—	0.1			
		4.5	—	—	0.26	—	0.33			I _{OL} = 4 mA
		6.0	—	—	0.26	—	0.33			I _{OL} = 5.2 mA
Input current	I _{in}	6.0	—	—	±0.1	—	±1.0	μA	Vin = V _{CC} or GND	
Quiescent supply current	I _{CC}	6.0	—	—	2.0	—	20	μA	Vin = V _{CC} or GND, I _{out} = 0 μA	

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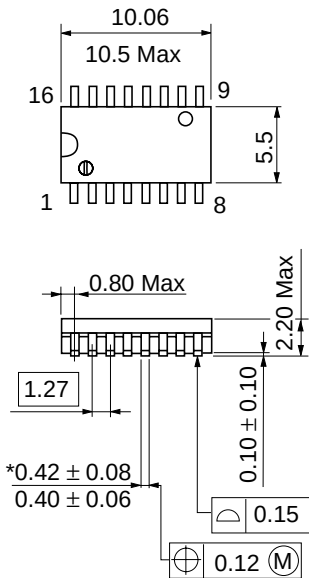
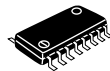
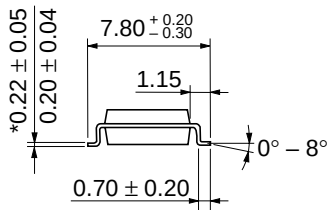
AC Characteristics (C_L = 50 pF, Input t_r = t_f = 6 ns)

Item	Symbol	V _{cc} (V)	Ta = 25°C			Ta = -40 to +85°C		Unit	Test Conditions
			Min	Typ	Max	Min	Max		
Maximum clock frequency	f _{max}	2.0	—	—	5	—	4	MHz	
		4.5	—	—	27	—	21		
		6.0	—	—	32	—	25		
Propagation delay time	t _{PLH}	2.0	—	—	175	—	220	ns	Clock to Q or $\overline{Q}$
		4.5	—	15	35	—	44		
		6.0	—	—	30	—	37		
	t _{PHL}	2.0	—	—	190	—	240	ns	Preset or Clear to Clock
		4.5	—	14	38	—	48		
		6.0	—	—	32	—	41		
Removal time	t _{rem}	2.0	25	—	—	32	—	ns	
		4.5	5	1	—	6	—		
		6.0	4	—	—	5	—		
Setup time	t _{su}	2.0	100	—	—	125	—	ns	
		4.5	20	4	—	25	—		
		6.0	17	—	—	21	—		
Hold time	t _h	2.0	0	—	—	0	—	ns	
		4.5	0	-4	—	0	—		
		6.0	0	—	—	0	—		
Pulse width	t _w	2.0	80	—	—	100	—	ns	
		4.5	16	5	—	20	—		
		6.0	14	—	—	17	—		
Output rise/fall time	t _{TLH}	2.0	—	—	75	—	90	ns	
		4.5	—	5	15	—	19		
		6.0	—	—	13	—	16		
Input capacitance	C _{in}	—	—	5	10	—	10	pF	

Unit: mm

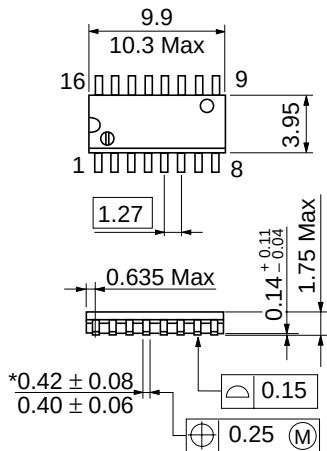
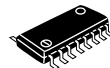
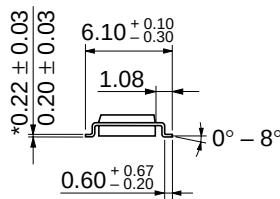


Hitachi Code	DP-16
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.07 g



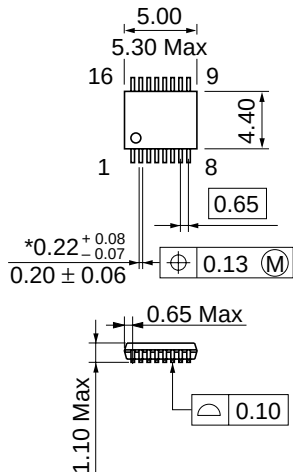
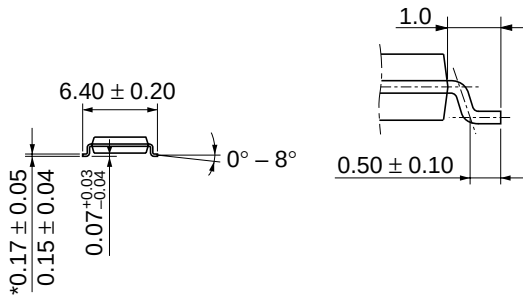
*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-16DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.24 g



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g



*Dimension including the plating thickness
Base material dimension

Hitachi Code	TTP-16DA
JEDEC	—
EIAJ	—
Weight (reference value)	0.05 g

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